## NSN 5961-00-825-9663

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-825-9663 **Inclosure Material:** Metal **Overall Length:** 0.405 inches **Overall Diameter:** 0.424 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-4 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.424 inches and 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 75.0 regulator voltage **Current Rating Per Characteristic:** 50.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 155.0 degrees celsius ambient air **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 tab, solder lug **Specification Data:** 80131-release2215 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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